Assessment and subject description

| Óbuda Universi Kandó Kálmán F | • | Electric | al Engir | eering | In | stitute of Microel | ectron | ics and T | echnology | |
|---|---|----------|------------|-------------|------|--------------------|--------|------------|-----------|--|
| | | | Ų | • | | s, KEEVR5ABN | | | | |
| Course: Electrica | l Enginee | ring | | | | | | | | |
| Responsible: | | | | | | |). | | | |
| | Andrea, | | | staff: | | | | | | |
| Prerequisites: | | none | | | | | | | | |
| Contact hours | Lecture: 2 Class discussion: 0 Lab hours: 0 | | | | | Tutoria | : 0 | | | |
| per week: | | | | | | | | | | |
| Assessment and | exam | | | | | | | | | |
| evaluation: | | | | | | | | | | |
| | | | Sı | ıbject desc | rip | tion | | | | |
| Learning objecti | | | to and | basic know | wle | dge of materials | scienc | ce. Relati | ons among | |
| preparation meth | | ture and | 1 propert | ies of mate | rial | 8. | | | | |
| Topics to be cove | ered: | | T • | | | | | *** | . | |
| | | | Topics | | | | | Week | Lessons | |
| Introduction to materials science. Relations between composition, structure, | | | | | | | e, | 1. | 2 | |
| processing and properties of materials. | | | | | | | | | - | |
| Structure of atoms. Bohr model and wave mechanics' models. The periodic | | | | | | | | | | |
| table. Characteristic parameters. Atomic bonding. Relation between bonding | | | | | | | | 2. | 2 | |
| and material beha | | | | | _ | | | | | |
| Crystal structure. Types of crystals, lattice parameters. Packing factors, densities. Real crystals. Types of defects, lattice vibrations. 3. | | | | | | | | 2 | | |
| | • • | A | | | | | | | | |
| Methods of investigation of crystal structure. Optical and electron | | | | | | | | | | |
| | | | | | | | | | 2 | |
| electron diffractio | | .1.1 . | | .1.1 . | | | | | | |
| Transport in materials. Equilibrium vs. non-equilibrium. Electrical and heat | | | | | | | | _ | • | |
| transport. Material transport: steady-state and non-steady-state diffusion. | | | | | | | | 5. | 2 | |
| Oxidation. Test 1 | | | | | | | | 6. | 2 | |
| Alloys. Phase transitions and phase diagrams. | | | | | | | | <u> </u> | 2 | |
| | | | | | | | | 7. | 4 | |
| Mechanical properties of materials. Deformation, stress and strain. | | | | | | | | 8. | 2 | |
| Ductility, toughness, hardness. Mechanical failures. | | | | | | | | | | |
| Electrical properties of materials. Band theory. Metals, semiconductors, insulators. | | | | | | | | 9. | 2 | |
| Magnetic properties of materials. Types of magnetism. Ferro- and | | | | | | | | | | |
| ferrimagnetism. Magnetic storage of information. | | | | | | | | 10. | 2 | |
| | <u> </u> | <u> </u> | | | sol | ids. Absorption. | | | | |
| Optical properties of materials. Light interaction with solids. Absorption, reflection, transmission, refraction, polarization and their relation to electron | | | | | | | | 11. | 2 | |
| structure. Light e | | | | | | | | | | |
| New results in Material Sciences | | | | | | | | 12. | 2 | |
| Test 2 | | | | | | | | 13. | 2 | |
| | | | | | | | | 13. | | |

Assessment and evaluation

<u>Requirements of the signature</u>: Regular class attendance is a prerequisite for receiving credit in the course. Course attendance is tracked and maximum 2 absences are allowed. Students whose absences exceed 2 will be dropped from the course. Laboratory mark should exceed 2.

Students will take two tests during the course. The minimum requirement to pass each test is to achieve 50% of total scores. Students can retake the test for free in case they do not reach the minimum requirements. Final correction opportunity is within the first 10 days of the examination period. (Aláíráspótló vizsga)

<u>Type of exam</u>: Written, covering the all topics of the course.

Evaluation of the mark: Mark is determined by the table below:

| Mark | Total score |
|------|-------------|
| 5 | 85-100 % |
| 4 | 74-84 % |
| 3 | 63-73 % |
| 2 | 50-62 % |
| 1 | 0-49 % |

Suggested material

Fundamentals of Materials Science and Engineering

William D. Callister, Jr.; David G. Rethwisch; 910 pages; John Wiley & Sons; 4 Edition (2013);

ISBN: 978-1-118-32269-7

Semiconductor Devices: Physics and Technology

Simon M. Sze, Ming-Kwei Lee; 592 pages; John Wiley & Sons; 3 Edition (2012); ISBN-10: 0470537949; ISBN-13: 978-0470537947

Comment: Learning materials will be uploaded in the Moodle.